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Magnesioreduction synthesis of Co-doped β -FeSi₂: mechanism, microstructure and improved thermoelectric properties

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Abstract

β -FeSi₂ and β -Co_{0.07}Fe_{0.93}Si₂ thermoelectric silicides were synthesized from Fe₂O₃ and Si powders using a magnesiothermic process. Detailed study of the reaction mechanism by X-ray diffraction reveals that liquid Mg is mandatory to initiate the reduction. After completion of the reaction in relatively short time (10 h at 1173 K), the magnesiosynthesized iron disilicides are characterized as powders with grain sizes ranging from 30 to 400 nm and containing a high concentration of stacking faults quantified for

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3 the first time using a dedicated refinement software. The thermoelectric properties of
4 spark plasma sintered pellets with submicrometric grain sizes, high stacking fault den-
5 sity and residual micro- to nanoporosities are presented and compared to corresponding
6 materials synthesized by conventional arc-melting process. Strong thermal conductiv-
7 ity reduction of 20 % at 773 K has been achieved thanks to the mesostructuration
8 induced by the magnesio-reduction. It results in an improved maximum figure-of-merit
9 ZT reaching 0.18 at 773 K for β -Co_{0.07}Fe_{0.93}Si₂.
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18 19 **Keywords**

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22 Iron silicide, Thermoelectrics, Magnesiothermy, Mesostructuration, Stacking faults, Thermal
23 conductivity
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28 29 **1 Introduction**

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31 Thermoelectric (TE) materials are being extensively investigated because they enable the
32 direct conversion of (wasted) heat into electricity, and *vice versa*, through highly reliable solid
33 state devices.^{1,2} The material performances are directly related to the TE figure-of-merit ZT
34 defined as:
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$$41 \quad ZT = \frac{\alpha^2}{\rho(\kappa_L + \kappa_e)} T \quad (1)$$

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48 where α is the Seebeck coefficient, ρ the electrical resistivity, κ_L and κ_e the lattice and elec-
49 tronic contributions to the total thermal conductivity κ and T the absolute temperature.
50 Large enhancement of ZT and subsequent conversion yield is however challenging due to
51 interrelated physical components. Common strategies consist on the one hand in the opti-
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3 mization of the power factor, $PF = \alpha^2/\rho$, essentially *via* doping and band engineering,³ and
4 on the other hand in the reduction of κ_L *via* nanostructuring, porosity/defects engineering
5 and complex alloying.⁴⁻⁶ In the past twenty years, these strategies successfully resulted in TE
6 materials with ZT much higher than 1.⁷⁻⁹ Most of these materials, including clathrates,¹⁰
7 Pd/Te-based alloys¹¹ or Hf-containing Heusler phases,¹² are however hardly industrializable
8 candidates because of time and energy consuming syntheses, poor mechanical properties and
9 most importantly chemical compositions including toxic and/or expensive constituents.¹³
10

11 From these points of view, β -FeSi₂ is considered as a reasonable candidate for large scale
12 application due to its extremely abundant and ecofriendly constituting elements, and good
13 oxidation resistance. However, the intrinsic TE properties of pristine FeSi₂ are poor, espe-
14 cially due to its high thermal conductivity (16 - 17 W m⁻¹ K⁻¹ at 273 K) and electrical
15 resistivity (5 - 10 m Ω m at 370 K).¹⁴ Doping with Co,^{14,15} Al,¹⁵ Mn¹⁶ or Cr¹⁴ efficiently
16 improves the maximum ZT to about 0.15. Moreover, the synthesis of β -FeSi₂ (space group
17 *Cmce*) by conventional metallurgical routes is facing the peritectoid decomposition in ϵ -FeSi
18 (s.g. *P2₁3*) and α -Fe_{1- δ} Si₂ (s.g. *P4/mmm*) above 1255 K,¹⁷ implying long annealing at
19 high-temperature to recover the β -phase. For such reasons, extensive research has been de-
20 voted to the development of alternative synthesis routes for nanostructured silicides with
21 reduced thermal conductivity adapted to large scale production. For example, mechanical
22 alloying^{14,18-20} or melt spinning²¹ followed by reactive sintering were used for the fabrication
23 of mesostructured and highly substituted β -FeSi₂. Recently, several studies reported the syn-
24 thesis of β -FeSi₂/Si(Ge) nanocomposites by the eutectoid decomposition of α -Fe_{1- δ} Si₂.²²⁻²⁵
25 The resulting microstructure consists in 10 to 200 nm Si(Ge) well-dispersed inclusions inside
26 a β -FeSi₂ matrix allowing a κ reduction up to 50 %. Controlled doping remains however
27 difficult by this approach resulting in materials with peak ZT rarely exceeding 0.1,²⁶⁻²⁹ but
28 reaching values as high as 0.4 - 0.6 when the doping is successful.^{19,25} More exploratory
29 synthesis routes such as laser sintering^{30,31} or gas-phase reaction³² were successful to obtain
30 β -FeSi₂ but they still remain more adapted to laboratory scale production.
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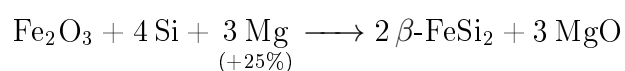
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3 Sen *et al.* reported an innovative synthesis of (doped) β -FeSi₂ nanopowders by magne-
4 sio-reduction of mixed oxide mixtures prepared by sol-gel method from tetraethylorthosilicate
5 (Si(OC₂H₅)₃) and ferric nitrate (Fe(NO₃)₃·9H₂O).^{33,34} The high reducing power of Mg allows
6 the reaction to be carried out in short reaction time (6 h) and at relatively low temperature
7 (1073 K) thus avoiding the post-synthesis annealing step. In addition, the powder obtained
8 by this process has grain sizes as small as 50 nm, which might be suitable for the prepa-
9 ration of nanostructured thermoelectrics. However, the as-reported synthesis procedure re-
10 mains hardly compatible with industrial scale production, mainly due to the numerous steps
11 involved (up to 6) including a time-consuming preparation of the oxide mixture (2 steps
12 totaling 18 h) from highly hygroscopic reactants.

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15 In the present article, a modified magnesioreduction synthesis for thermoelectric β -FeSi₂
16 and β -Co_{0.07}Fe_{0.93}Si₂ powders with 30 - 400 nm grain sizes is described. The preparation of
17 the oxide precursor mixture is realized in a single step by ball-milling (Co-doped) Fe₂O₃ and
18 Si. This offers many advantages such as a higher scalability perspective, the use of cheap, air
19 stable and non-hazardous precursors and a final yield greater than 98 %. The chemical reac-
20 tivity has been followed by powder X-ray diffraction during the whole process to optimize the
21 temperature/duration of the thermal treatment. The crystal structure, refined for the first
22 time using a dedicated software to analyze the impact of stacking faults on Bragg reflections,
23 and the microstructure, characterized by scanning and transmission electron microscopies,
24 are presented on as-synthesized powders and spark plasma sintered pellets. Finally the im-
25 proved TE properties are discussed toward the influence of the microstructure and compared
26 to similar materials synthesized by conventional arc-melting/sintering/annealing route.

2 Experimental methods

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The experimental set-up for the magnesioreduction synthesis (MR) is described in more de-
tails in our previous articles.^{35,36} For undoped β -FeSi₂, a precursors mixture is first prepared

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3 by dry ball-milling stoichiometric amounts of Fe₂O₃ (Merck, > 99 %) and Si powder (Ven-
4 tron, 99.9 %) using WC vial and balls (ball-to-powder ratio of 5 : 1) with rotation speed of
5 650 rpm for 4 h under air atmosphere. Good control of milling conditions of precursors was
6 found essential to prevent contamination by WC during the milling and formation of side-
7 products (FeSi, Fe₃Si, unreacted Si) during the magnesio-reduction process. The precursor
8 mixture is cold pressed (100 MPa) in Ø 10 mm pellets with 2 mm height and placed with
9 adequate amount of Mg turnings according to:



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23 in a clamped Mo crucible. The latter is heated under Ar protective atmosphere at a rate of
24 100 K h⁻¹ up to 1173 K, maintained at this temperature for 10 h and cooled down to room
25 temperature by switching off the furnace. The reaction product is recovered by opening
26 the crucible and MgO by-product is removed by soaking the as-synthesized powder twice in
27 diluted hydrochloric acid (2 wt.%) and washing three times with distilled water and once
28 more with ethanol before being dried at 353 K overnight. Densified β-FeSi₂ pellets are
29 obtained by spark plasma sintering (SPS, FCT HP-D-10 apparatus) the ‘washed’ powders in
30 Ø 10 mm graphite dies at 1323 K - 80 MPa for 30 min followed by 24 h annealing at 1100 K
31 in an evacuated silica tube.

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34 For the synthesis of β-Co_{0.07}Fe_{0.93}Si₂, the addition of Co₃O₄ to Fe₂O₃ and Si during the
35 ball-milling preparation of the precursor mixture leads to the formation of CoSi₂ during
36 the magnesio-reduction process, attributed to an uneven distribution of Co in the mix-
37 ture. Starting from a properly doped Co_{0.14}Fe_{1.86}O₃ precursor allows Fe and Co to be
38 homogeneously distributed at the atomic scale and the probability to form side-products
39 is greatly reduced. Co_{0.14}Fe_{1.86}O₃ is synthesized by dissolving stoichiometric proportions
40 of Co(NO₃)₂·6H₂O (Fluka, ≥ 98 %) and Fe(NO₃)₂·9H₂O (Fluka, ≥ 98 %) in a minimum
41 amount of distilled water and by calcinating the mixture at 773 K for 6 h in air. According to

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3 X-ray diffraction (XRD), the obtained red powder is single phase α - $\text{Co}_x\text{Fe}_{2-x}\text{O}_3$ (s.g. $R\bar{3}c$)
4 with $a = 5.0327(1)$ Å and $c = 13.7413(4)$ Å as determined by Le Bail refinement of the
5 diffraction patterns (fig. S1). The lattice parameters are significantly different from those
6 reported for pure α - Fe_2O_3 ($a = 5.0368(1)$ Å and $c = 13.7601(3)$ Å³⁷) and energy disper-
7 sive spectroscopy (EDS) elementary analyses indicate a Co concentration of approximately
8 2 at.% in agreement with the targeted composition.
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15 The conventional synthesis of β - FeSi_2 and β - $\text{Co}_{0.07}\text{Fe}_{0.93}\text{Si}_2$ consisted in arc-melting (AM)
16 stoichiometric amounts of the metallic elements three times to ensure homogenization. The
17 resulting ingots are milled, SPS sintered at 1223 K and 90 MPa for 5 min and finally annealed
18 for 60 h at 1123 K in evacuated silica tubes.
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23 The crystal structure and purity of the samples are checked by powder XRD using a
24 Bruker D8 Advance diffractometer working in the modified Bragg-Brentano geometry with
25 a monochromatized Cu $K\alpha_1$ radiation ($\lambda = 1.54059$ Å) and equipped with a LynxEye fast
26 detector. Structural parameters are determined by Rietveld refinements of the XRD patterns
27 using the FullProf or FAULTS softwares^{38,39} included in the FullProf Suite package.⁴⁰ Scan-
28 ning electron microscopy (SEM) in secondary and backscattered electrons modes and EDS
29 are performed on a JEOL JSM 7100 F microscope equipped with an Oxford EDS SDD X-
30 Max spectrometer. Transmission electron microscopy (TEM) is performed on a JEOL 2100
31 LaB₆ instrument operating at 200 kV and equipped with high resolution Gatan US1000 and
32 Orius SC 200D cameras and EDS Oxford 80 mm² SDD spectrometer. Preparation of the
33 powder samples for SEM analyses consists in the deposition of powder on carbon tape fol-
34 lowed by metallization with carbon while for TEM analyses small amount of the powder is
35 sonicated in absolute ethanol and deposited for drying on a carbon coated copper grid.
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49 The thermal diffusivity (D) is measured by the laser flash analysis (LFA) method on
50 \varnothing 10 mm and 2 mm thick samples coated with graphite using a Netzsch LFA 467 Hyper-
51 Flash equipment under N_2 atmosphere. The thermal conductivities are then calculated by
52 the relation $\kappa = D \cdot C_p \cdot d$ with C_p the specific heat of the sample determined thanks to a
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Netzsch *Pyroceram* reference and the density d determined by the Archimede method in absolute ethanol. Measurements of the Seebeck coefficient and electrical resistivity are realized simultaneously on $6 \times 2 \times 2$ mm³ bars using a ZEM3 (ULVAC-RIKO Inc., Yokohama, Japan) equipment under He atmosphere.

3 Result and discussion

3.1 Magnesioreduction process

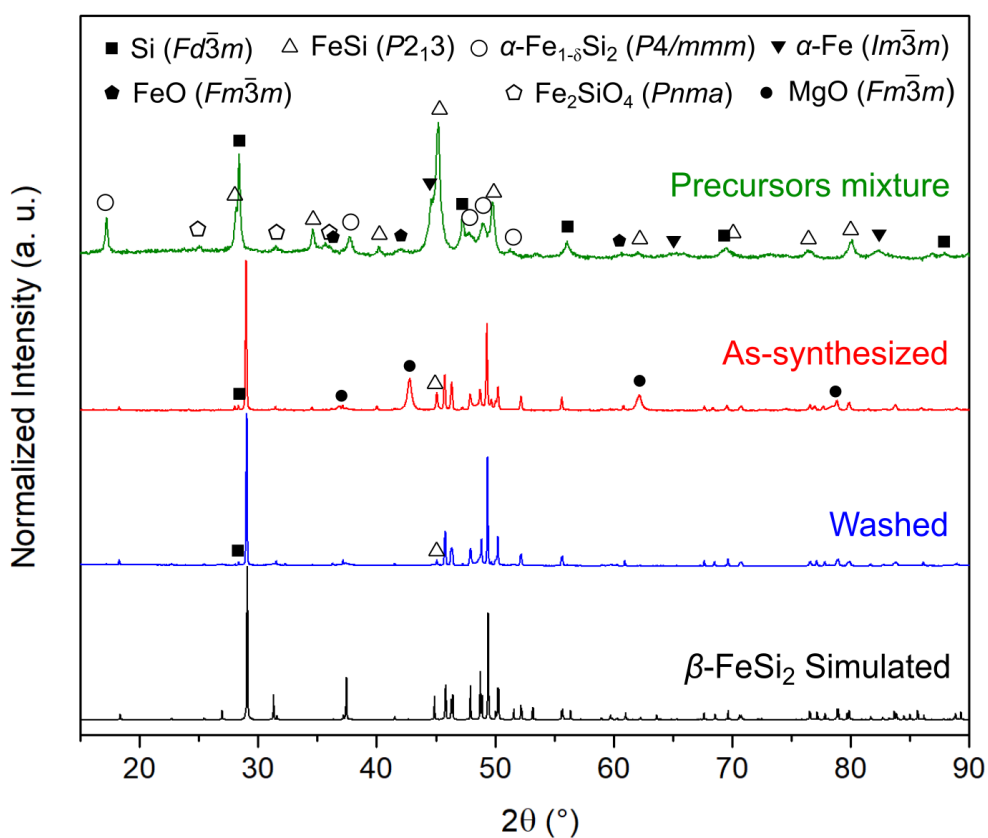
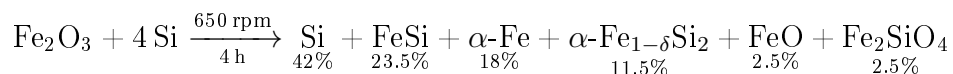


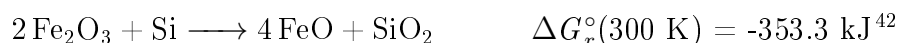
Figure 1: XRD patterns of the precursor mixture (green), as-synthesized (red) and HCl-washed (blue) MR β -FeSi₂ powders, as well as simulated pattern for β -FeSi₂⁴¹ (black). Intensity discrepancies between some peaks in the experimental and theoretical β -FeSi₂ patterns are linked to the presence of (100)[011]/2 stacking faults in the crystals (see text for details).

The XRD pattern of the precursors mixture obtained by ball-milling Fe₂O₃ and Si is

shown in fig. 1. Up to six crystalline phases have been identified indicating a reactive milling. The relative concentrations (mol.%) of the products in the precursors mixture are determined by Rietveld refinement (fig. S2a):



Interestingly, Fe^{3+} (Fe_2O_3) is entirely reduced in Fe^{2+} (FeO , Fe_2SiO_4) or metallic Fe (Fe , FeSi , $\alpha\text{-Fe}_{1-\delta}\text{Si}_2$) during the milling process. Solid state redox reactions occur with Si playing the role of reducing agent most probably according to:



Both reductions are thermodynamically possible at room temperature in view of their large negative Gibbs free energies. The activation energies are overcome by the highly energetic shocks occurring in the milling vial. Analogous reactions are reported for higher manganese silicides where MnO is reduced by Si in similar milling conditions.³⁶

As a result, SiO_2 has to be present in the precursor mixture. Its amorphous nature is suggested by the broad deviation of the background of XRD patterns around 22° associated to silica glass.⁴³ The Si/Fe atomic ratio of 1.5 determined from Rietveld refinement is much smaller than the value of about 2 expected from the reactant quantities and confirmed by SEM-EDS analyses. A SiO_2 concentration of about 23 mol.% in the precursor mixture can thus be estimated. Moreover, freshly reduced metallic Fe is expected to react with Si by mechanical alloying forming FeSi and $\alpha\text{-Fe}_{1-\delta}\text{Si}_2$ as already reported in the literature.^{18,44,45} The formation of the high temperature allotrope of the disilicide upon milling highlights the

energetic conditions in the vial during the milling. Fe_2SiO_4 is probably formed in a similar manner from FeO and SiO_2 . SiO_2 , FeO and Fe_2SiO_4 are the remaining oxide phases to be reduced by Mg during the magnesio-reduction process.

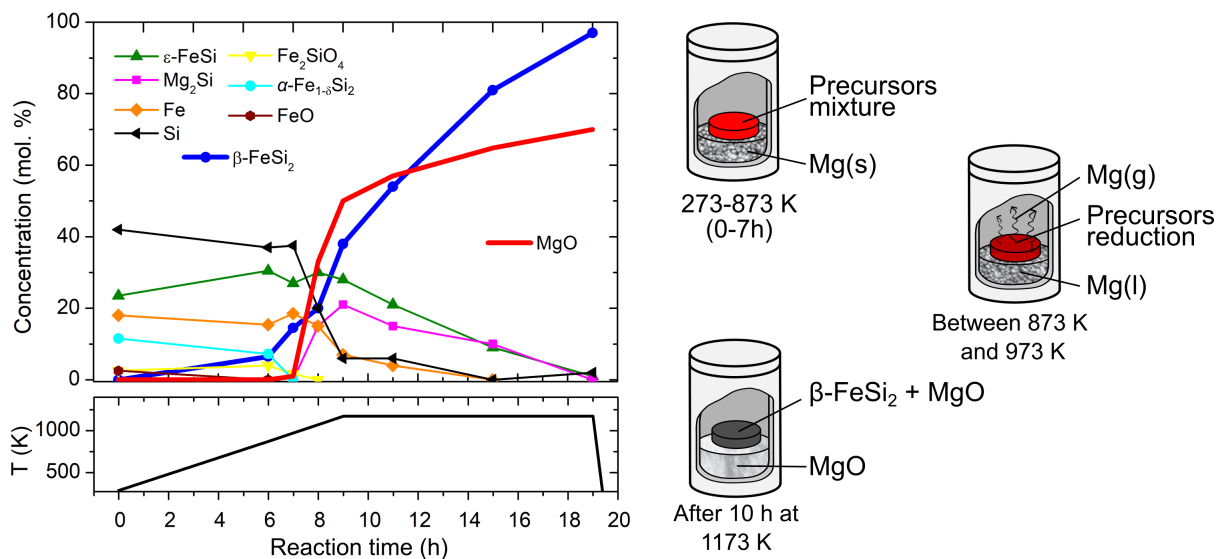


Figure 2: (left) Evolution of the sample composition during the magnesio-reduction synthesis of $\beta\text{-FeSi}_2$ determined by Rietveld refinements. The relative deviation on the concentrations is estimated to be well below 5 % according to measurement conditions, quality of the fits and Ref.⁴⁶ (right) Schemes of the crucible at three important stages of the reaction: heating-up (top), melting of Mg and reduction of the precursor mixture (middle), completed reaction after 19 h (right) (s: solid, l: liquid, g: gas).

The thermal cycle used for the magnesiothermic reaction consists in a heating ramp up to 1173 K in 9 h followed by a 10 h isothermal plateau. To better understand the reaction mechanism, the reactor was quenched in cold water at different times of the process and the phases in presence were quantified by Rietveld refinement of XRD patterns. The evolution of phase concentrations (excluding MgO) as a function of the reaction time is presented in fig. 2 with lines+symbols while the overall content in MgO in the reaction media is displayed with a red line. The fitted XRD pattern and refined structural parameters and details about the refinement procedure can be found in fig. S2a-h and tables S1-S9.

During the first 6 hours of the reaction, no significant changes can be observed indicating that Mg is quite unreactive below 873 K toward the species in presence. Only $\alpha\text{-Fe}_{1-\delta}\text{Si}_2$

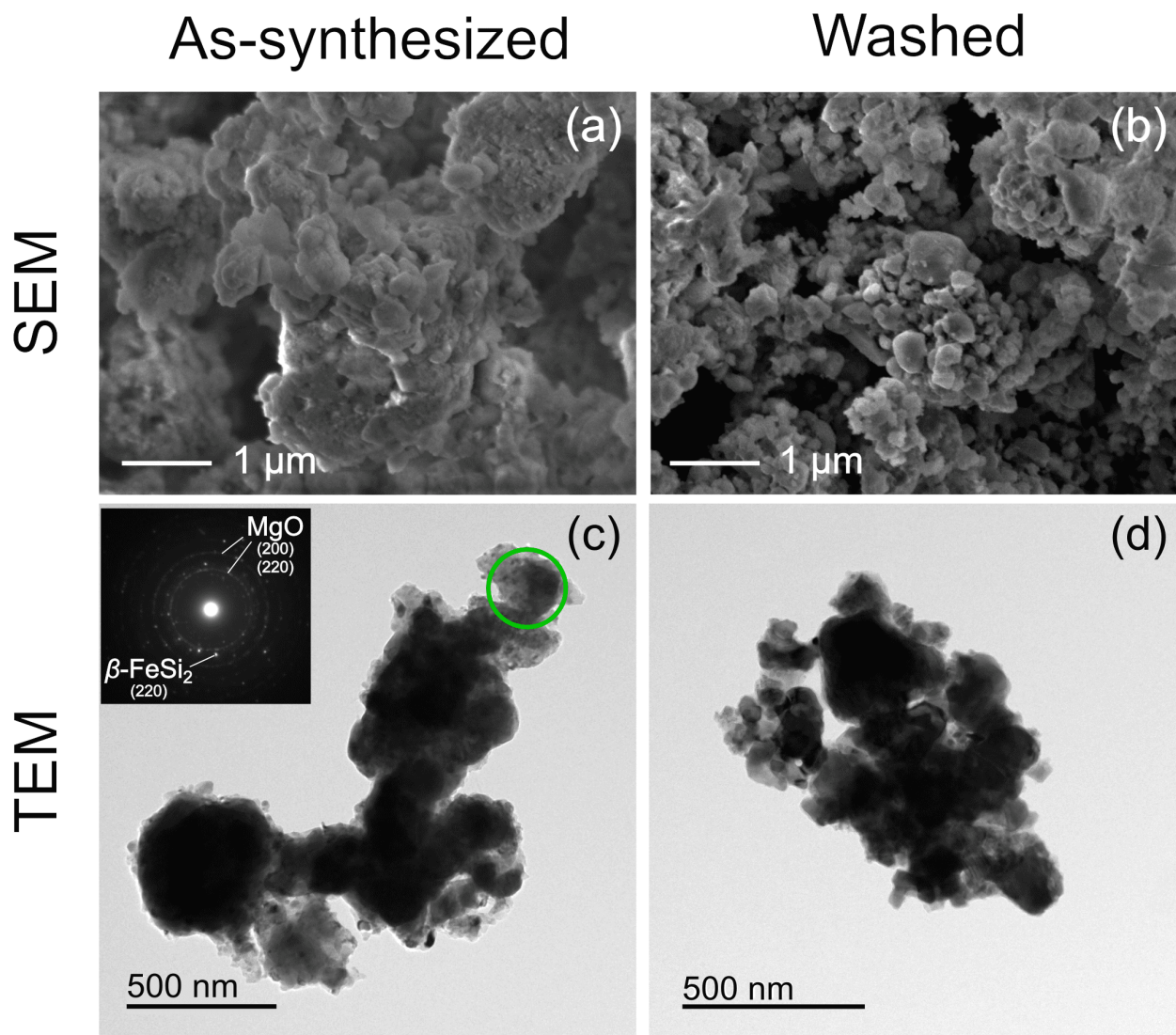
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3 slowly transforms in β -FeSi₂ which is the thermodynamically stable allotrope in this tem-
4 perature range. Between 873 and 973 K, the reduction process starts as indicated by the
5 formation of MgO (1 mol.%). Interestingly, it corresponds well to the melting temperature
6 of Mg (melting point $T_m = 922$ K) and suggests that liquid Mg with high vapor pressure
7 (383 Pa at T_m) is required to initiate the reduction.⁴⁷ At 1073 K, MgO and newly formed
8 Mg₂Si intermetallic represent as much as 33 and 16 mol.% of the whole reaction media,
9 respectively. The heat produced locally by the highly exothermic reduction of SiO₂ by
10 Mg ($\Delta H_r(1200\text{ K}) = -344\text{ kJ mol}^{-1}$ ⁴²) is expected to intensify the reactivity of Mg and to
11 enhance the reaction rate, in a scenario close to a combustion synthesis.^{48,49} The β -FeSi₂ con-
12 centration strongly increases (+23 %) between 873 K and 1173 K which is mostly attributed
13 to the solid-state reaction between Fe (-17 %) and Si (-30 %).

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15 At 1173 K, the reaction media is composed of β -FeSi₂, FeSi, Mg₂Si and some unreacted Si
16 and Fe giving an overall Si/Fe metal ratio of 1.8. This is higher than the 1.5 ratio determined
17 for the precursor mixture but still lower than the expected value of 2. This suggests that
18 the reduction of amorphous SiO₂ is not yet completed at the end of the heating ramp.
19 As indicated by the decrease of Mg₂Si content and the increase of Si/Fe ratio during the
20 isothermal plateau, amorphous SiO₂ is slowly reduced by highly reactive Mg₂Si^{50,51} according
21 to the reaction:



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23 Finally, after 10 h at 1173 K, XRD pattern shows that MgO and β -FeSi₂ are the main
24 phases in the reduced pellets with only small amounts of residual Si and FeSi.

25
26 Weighing the pellets before the reaction and the powders after HCl-washing indicates
27 reaction yields typically higher than 98 % using this process.



38 Figure 3: (a-b) Secondary electron SEM and (c-d) brightfield TEM images of the as-
39 synthesized (left) and HCl-washed (right) MR $\beta\text{-FeSi}_2$ powder. The electron diffraction
40 pattern shown in inset was taken at the green circle in (c).
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43 MR-powder microstructure

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46 SEM images of the as-synthesized MR $\beta\text{-FeSi}_2$ powder (fig. 3a) reveal aggregated particles
47 with sizes below 400 nm. SEM-EDS elementary analyses confirm the Si/Fe metal ratio of
48 2 and the presence of Mg (60 at.%) ascribed to MgO. Typical TEM brightfield image of an
49 aggregate is shown in fig. 3c. According to TEM-EDS analyses, the large darker areas at the
50 center are mostly composed of Fe and Si while the surrounding brighter area corresponds to
51 MgO. In addition, electron diffraction pattern in fig. 3c shows diffuse rings corresponding
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3 to MgO (s.g. $Fm\bar{3}m$, $a = 4.21 \text{ \AA}$)⁵² while sharp spots are ascribed to β -FeSi₂.⁴¹ In light
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5 of these observations, the aggregate irregular shape of as-synthesized powder derives from
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7 the association of well-crystallized β -FeSi₂ particles (darker areas) being embedded inside
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9 a nanocrystalline MgO matrix (bright area). We hypothesize here that the MgO layer
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11 surrounding the β -FeSi₂ grains plays a significant role during the heat treatment to limit the
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13 grain growth and stabilize the submicronic size of the silicide.
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15 After diluted hydrochloric acid washing, the diffraction peaks of MgO disappear on the
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17 XRD patterns, indicating its elimination at least below the detection level of the technique
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19 (fig. 1). The almost entire dissolution of MgO, as well as the homogeneous insertion of
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21 cobalt in the doped samples, are confirmed by SEM/TEM-EDS analyses.
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23 Removal of the MgO layer reveals the morphology of the β -FeSi₂ particles (fig. 3b,d)
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25 having sizes spanning from 30 nm to about 400 nm, suggesting that the present magne-
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27 sioreduction process produces powders with a slightly larger average size than the process
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29 described by Sen *et al.*³³ We attribute it to the smaller size of the oxide particles, lower
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31 reaction temperature (-100 K) and presence of MgO diluent in their precursor mixture. In
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33 our case, adding MgO diluent was found to considerably reduce the reaction kinetics.
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37 3.2 Crystal structure

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39 As reported by Dusausoy *et al.*,⁴¹ β -FeSi₂ crystallizes in the orthorhombic $Cmce$ space group
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41 with lattice parameters $a = 9.8774(3) \text{ \AA}$, $b = 7.8128(3) \text{ \AA}$ and $c = 7.8272(3) \text{ \AA}$. This struc-
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43 ture type derives from the fluorite-type structure by strongly distorting the [Si₈] cubes into
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45 irregular prisms where Fe-atoms occupy alternatively one half of the central sites (fig. 4a,b).
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47 In this initial description of the crystal structure, two independent Fe-sites are distributed
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49 over two kind of layers stacked along the a -axis (fig. 4a): the layer 1 contains the Fe1
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51 atoms in $8d$ Wyckoff site surrounded by [Si₈] trapezoid-based prisms, the layer 2 contains
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53 the Fe2 atoms in $8f$ Wyckoff site coordinated by similar [Si₈] trapezoid-based prisms with
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55 additional torsion angle between the rectangular faces. This structure of β -FeSi₂ can also
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be alternatively described as another layered one with ABAB stacking mode along the [100] direction, as shown in fig. 4a. While the individual layers are structurally identical, the layer A transforms into the layer B by the translation vector $x + 1/2, y + 1/2, z$, as represented in the projections along the a -axis of the layers in fig. 4c. In this description, each layer is composed of the layer 1 (fig. 4b) sandwiched between two half of the layer 2, and the pseudo-cubic layer 2 is build from the interaction of the A and B layers.

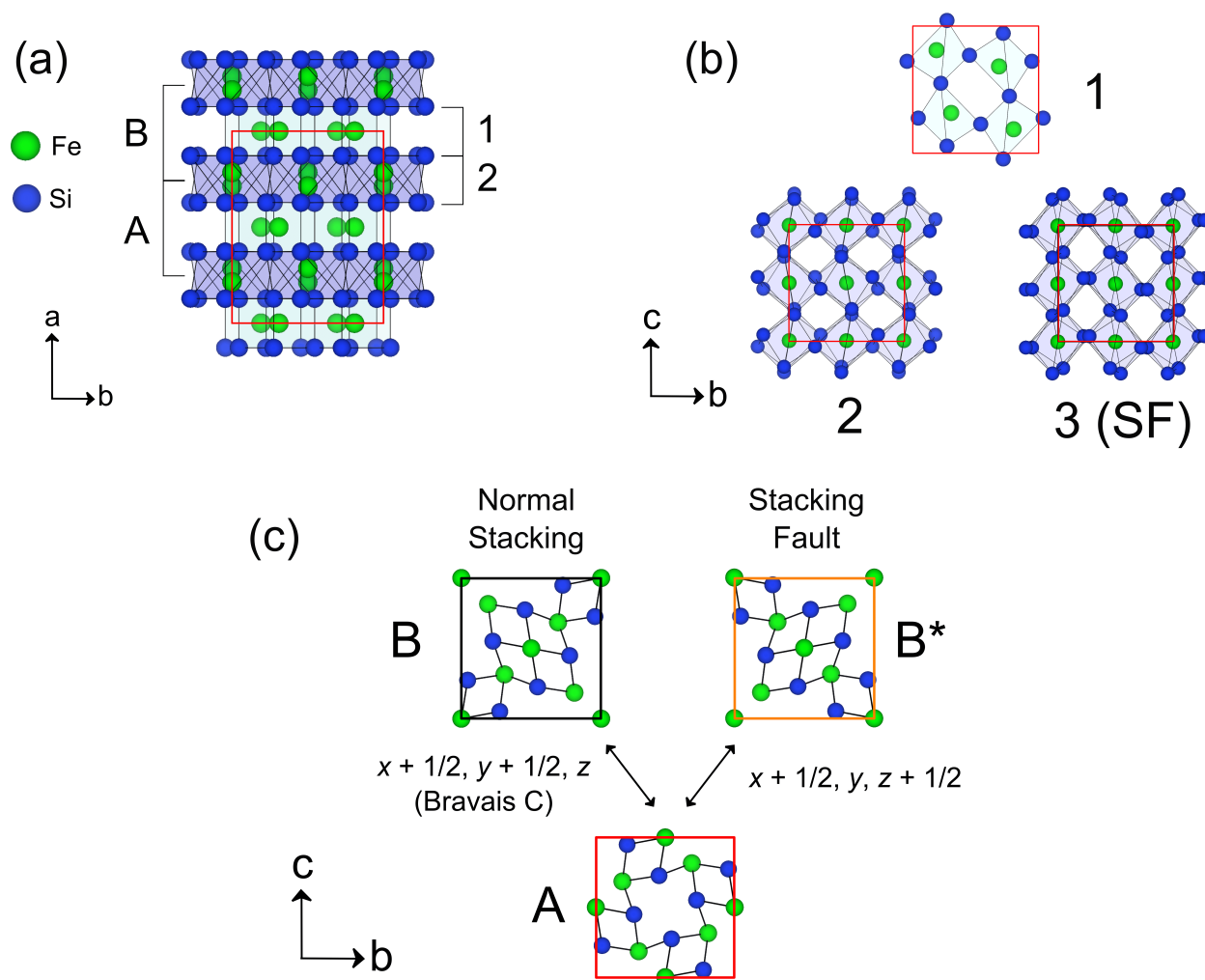


Figure 4: (a) c -axis projection of the crystal structure of β -FeSi₂ reported by Dusausoy *et al.*⁴¹ showing the Fe@[Si₈] networks and the ABAB stacking mode; (b) a -axis projections of the pseudo-cubic networks 1, 2 and 3; (c) a -axis projections of the normal stacking A and B layers and alternative stacking layer B* along with related displacement vectors.

However, β -FeSi₂ is known to accommodate high concentration of intrinsic stacking faults

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3 with displacement vector $(100)[011]/2$ as reported by Zheng *et al.*⁵³ and confirmed by Yamane
4 *et al.*⁵⁴ In other words, the expected AB stacking is randomly replaced by an AB* one
5 where the B* layer is obtained by a $x+1/2, y, z+1/2$ translation of the A-layer (fig. 4c).
6
7 A consequence of these stacking faults is the formation of a third type of Fe@[Si₈] network
8 (layer 3 in fig. 4b) at the interface of the stacking fault, which can be considered as a twinned
9 version of the layer 2,⁵³ with minor differences in the Fe-atom coordination sphere.
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13 In the case of the magnesio-reduced powders, the presence of the stacking faults (SF) is
14 highlighted by an important XRD peak shape broadening of the hkl reflections with $k+l \neq 2n$
15 (fig. 1) corresponding to diffuse streaks observed in the electron diffraction pattern along the
16 a^* -direction for this condition (fig. 5a). Dark-field images obtained from the diffuse streaks
17 of a crystal oriented along the $[0\bar{1}2]$ zone axis (fig. 5b) clearly reveal a high density of planar
18 defects. High resolution TEM image of this defective crystal (fig. 5c) shows 4.9 Å (*i.e.* $a/2$)
19 thick layers perpendicular to the $[100]$ direction and AB or AB* stacking.
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23 As pointed out by Yamane *et al.*,⁵⁴ the density of SF in β -FeSi₂ is strongly dependent
24 on the synthesis method. Indeed, pulverized crystals grown in relatively mild conditions,
25 *e.g.* metal flux or chemical transport methods, are found to be relatively free of SF while
26 polycrystalline samples prepared for example by conventional fusion/solidification or powder
27 metallurgical methods are more affected. In order to quantify the probability of SF in
28 our samples, the general recursion method for crystals containing planar faults developed
29 by Treacy *et al.*³⁹ has been applied to both pristine and Co-doped β -FeSi₂ prepared by
30 magnesio-reduction.
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34 The SF have been taken into account in the modeling of the X-ray diffraction data using
35 the dedicated FAULTS software.³⁸ For this, half a unit cell along the a -axis, corresponding
36 to a single layer A (fig. 4), was considered along with two possible displacement vectors,
37 $x + 1, y + 1/2, z$ and $x + 1, y, z + 1/2$ corresponding to the normal and faulty stacking,
38 respectively. Using this approach, the patterns were refined by optimizing the stacking
39 fault probability, the lattice and atomic parameters and the peak profile function. Refined
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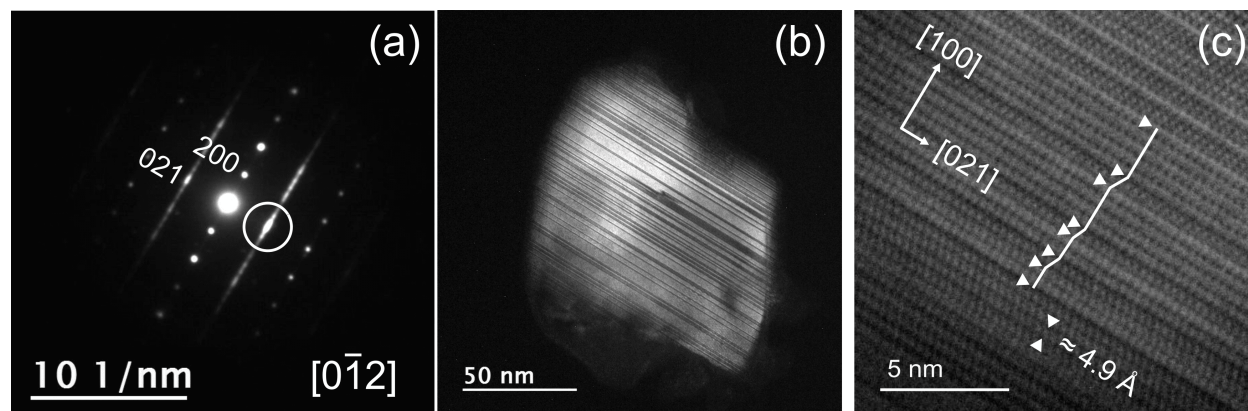


Figure 5: (a) Electron diffraction pattern of MR β -FeSi₂ taken along the $[0\bar{1}2]$ zone axis showing diffuse streaks for hkl reflections with $k+l \neq 2n$. (b) Dark-field image using the diffuse streak (white circle) revealing high density of planar defects in MR FeSi₂(c) HRTEM image showing the stacking faults indicated with white arrows.

XRD patterns are shown in fig. 6 and refined structural parameters summarized in table 1.

The atomic coordinates remain almost unchanged compared to Dusausoy's structural model and the atomic displacement parameters have regular values for intermetallic compounds.

The SF probabilities were found to be close to 15 % for both compositions. This value is similar to the ratios reported by Yamane *et al.* for β -FeSi₂ samples synthesized by powder metallurgy methods.⁵⁴ As pointed out by Zheng *et al.*,⁵³ the layer 3 exhibits a twin-like structure, as if the b and c axes were exchanged in the defect layer. Thus with increasing the SF concentration, one expects the b and c lattice parameters to converge to an average value between those in the regular lattice. Accordingly, the b and c lattice parameters in the MR powders are rather close from each other. Interestingly, the lattice constant a of the Co-doped sample increasing from 9.88240(2) Å to 9.89838(8) Å seems to be the only structural parameter affected by the insertion of Co in the structure. This is consistent with Hesse's work⁵⁵ reporting a linear increase of a with increasing Co substitution and an expected value of about $a = 9.905$ Å for β -Co_{0.07}Fe_{0.93}Si₂.

Table 1: Lattice parameters, atomic coordinates, isotropic thermal displacement parameters and stacking fault propability (SF) extracted from the Rietveld refinement of the HCl-washed MR β -FeSi₂ and MR β -Co_{0.07}Fe_{0.93}Si₂ XRD patterns

		MR β -FeSi ₂	MR β -Co _{0.07} Fe _{0.93} Si ₂
	a (Å)	9.88240(2)	9.89838(8)
	b (Å)	7.81651(2)	7.81778(8)
	c (Å)	7.83428(2)	7.82839(8)
	x	0.129(1)	0.128(1)
Si (16g)	y	0.273(1)	0.276(1)
	z	0.049(1)	0.045(1)
	x	0.124(1)	0.124(1)
Si (16g)	y	0.049(1)	0.046(1)
	z	0.272(1)	0.273(1)
	B_{iso} (Å ²)	0.4(1)	0.2(1)
	y	0.309(1)	0.310(1)
Fe2 (8f)	z	0.312(1)	0.310(1)
	x	0.216(1)	0.216(1)
Fe1 (8d)	B_{iso} (Å ²)	0.2(1)	0.1(1)
	SF (%)	14.8(1)	18.5(3)

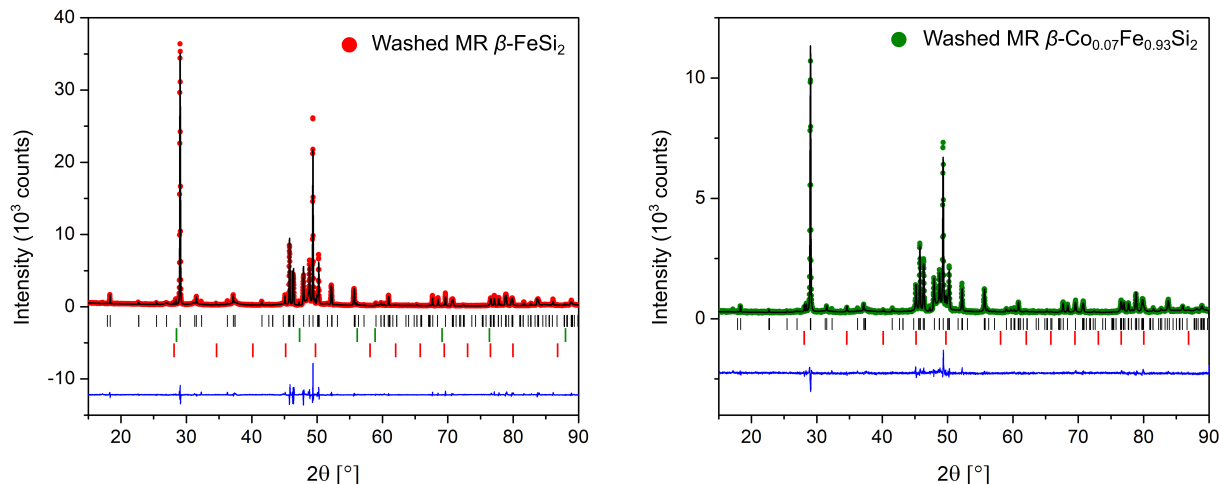


Figure 6: Rietveld refinement of the washed MR β -FeSi₂ (left) and MR β -Co_{0.07}Fe_{0.93}Si₂ (right) powder XRD. The experimental data are plotted in colored symbols, the calculated one with a black line and the difference with a blue line. The vertical ticks indicate the Bragg peak positions for β -FeSi₂ (black), FeSi (red) and Si (green).

3.3 Densified pellet microstructure

Any attempts to obtain densified pellets by spark plasma sintering below the decomposition temperature of β -FeSi₂ resulted in materials with low relative density (< 85 %) and were consequently abandoned. Pellets with 94 % and 97 % relative density were prepared from magnesio-reduced (MR) and arc-melted (AM), respectively, β -FeSi₂ and β -Co_{0.07}Fe_{0.93}Si₂ powders by SPS at 1323 K followed by 24 h annealing at 1100 K to recover the expected β -phase. Backscattered electron SEM images and EDS mappings of polished pellet surfaces obtained from the MR process reveal relatively homogeneous chemical composition (fig. 7) with the exception of small amount of FeSi impurity as well as a few WSi₂ particles certainly coming from WC contamination during the early precursor milling. SEM-EDS elementary analyses realized on the Co-doped samples synthesized by MR or conventional AM routes give a similar global Co concentration of about 2 at.% in good agreement with the targeted composition. None of EDS spectra measured inside the grains show the presence of magnesium, indicating the absence of significant contamination of the silicides by this element.

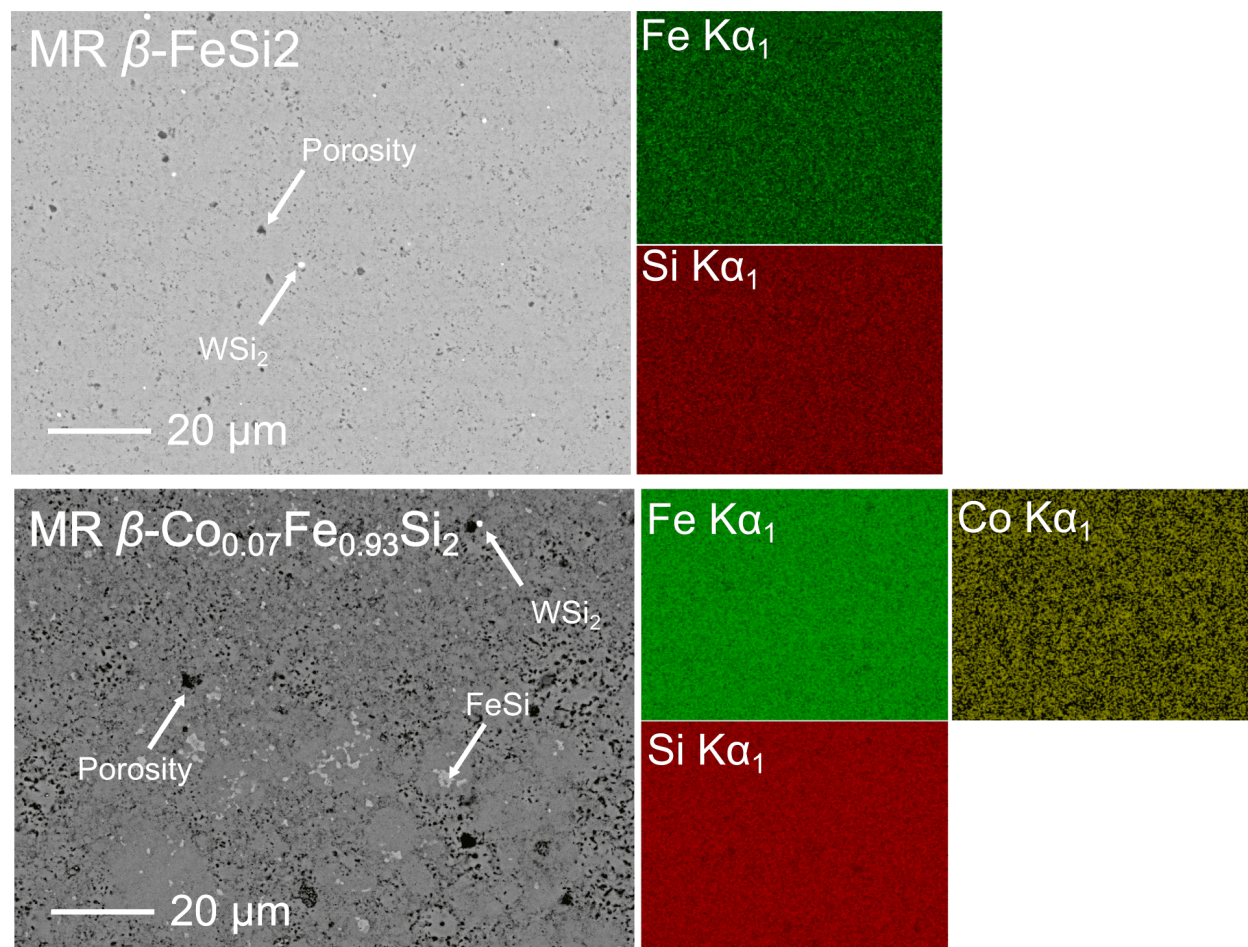


Figure 7: Backscattered electron SEM images and corresponding EDS mappings of the polished surface of undoped MR β -FeSi₂ (top) and MR β -Co_{0.07}Fe_{0.93}Si₂ (bottom) densified pellets.

Secondary electrons SEM images of the broken cross-section of undoped β -FeSi₂ densified pellets are shown in fig. 8 for MR and AM samples. The microstructure of the AM sample is relatively common for sintered iron silicides prepared by fusion-solidification techniques^{15,18} and the particle sizes span from 1 μ m to tens of μ m. Porosity is hardly visible and only a few submicronic pores can be detected at high magnification in agreement with the high density (97 %) measured by the Archimede method. In the case of the MR samples, the microstructure is significantly different with less well-faceted particles and smaller average grain size (mainly from 500 nm to 1 μ m range). By analogy with our previous report on higher manganese silicides and TEM analysis (fig. 3d) prior to SPS, we assume here that

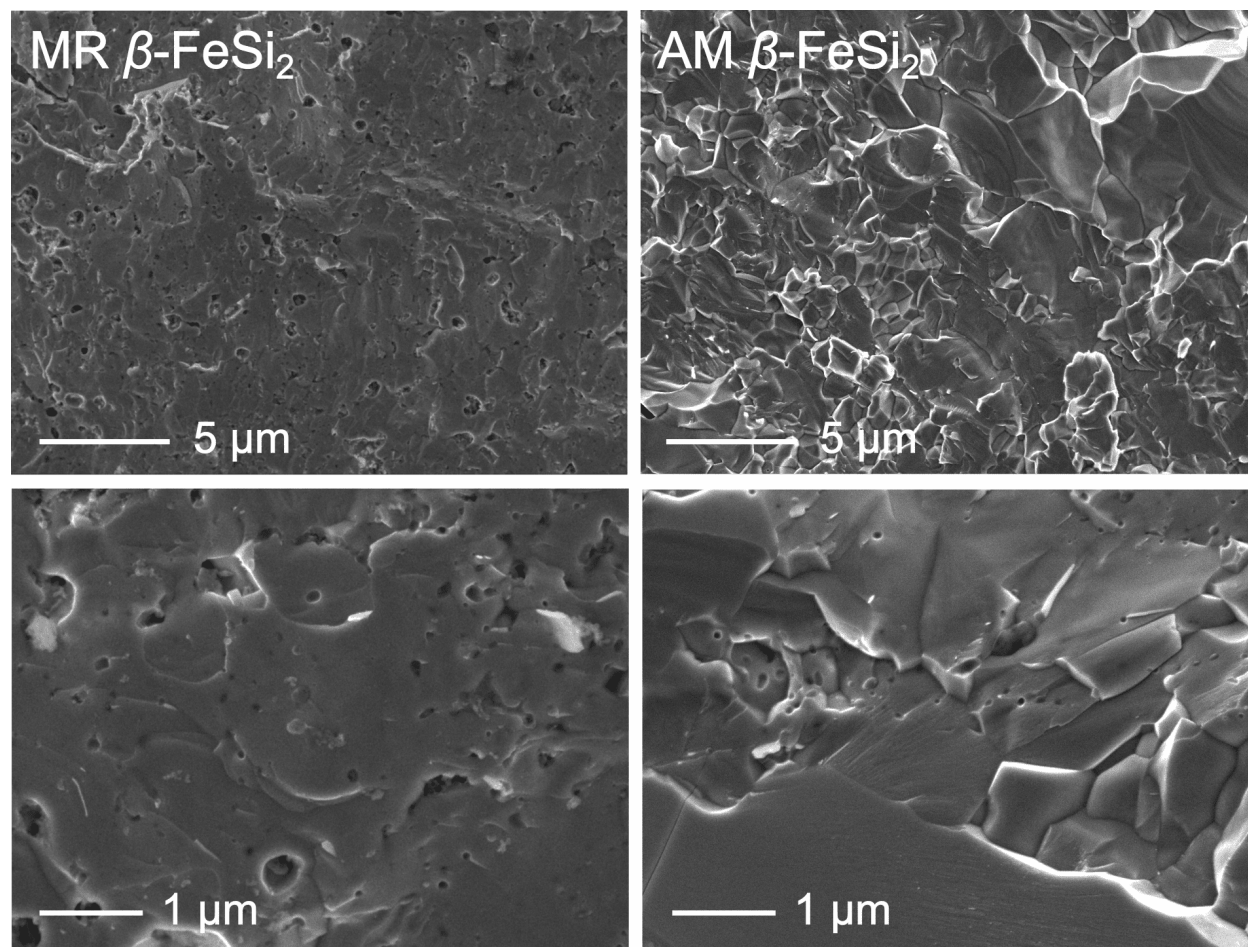


Figure 8: Secondary electron SEM images of broken cross-sections of MR (left side) and AM β -FeSi₂ (right side) at two different magnifications.

these MR particles are single crystals. As a consequence of the submicronic grain sizes, numerous residual porosities with sizes from 500 nm down to few tens of nanometers are observed for MR samples which is consistent with the larger deviation from full densification (94 %).

XRD realized on crushed pellets are presented in fig. 9a for undoped and in fig. S3 for Co-doped samples. Lattice and structural parameters extracted by refinements are presented in table 2 and table S10. The lattice constants and atomic coordinates are comparable for the corresponding compositions. More particularly, the similar a parameters for the doped samples suggest equivalent Co substitution in agreement with SEM-EDS results. The SF probability is however systematically higher for MR (≈ 10 %) than for AM samples (≈ 3 %).

The density of SF in the samples can be directly appreciated by comparison of the (312) Bragg reflections (fig. 9b) which become significantly less intense and broader with increasing SF probability. This result confirms that the synthesis route has a strong influence on the SF density in β -FeSi₂ even after high-temperature sintering/annealing steps.

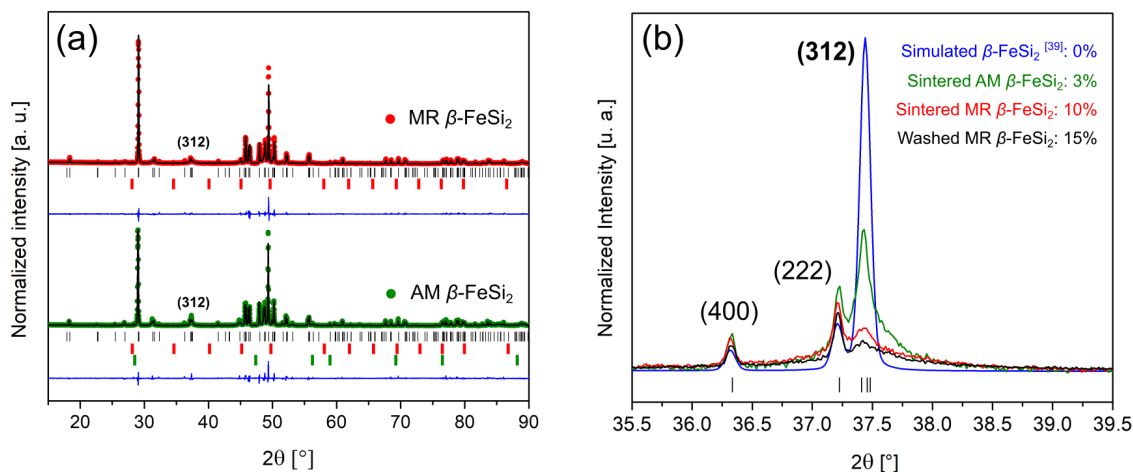


Figure 9: (a) FAULTS refined powder XRD patterns of sintered MR β -FeSi₂ (red) and AM β -FeSi₂ (green). The experimental data are plotted in colored symbols, the calculated one with a black line and the difference with a blue line. The vertical ticks indicate the Bragg peak positions for β -FeSi₂ (black), FeSi (red) and Si (green). (b) Influence of the stacking fault density on the (312) diffraction peak profile and intensity.

Table 2: Lattice parameters, stacking fault probability and impurity content for spark plasma sintered MR FeSi₂, AM FeSi₂, MR Co_{0.07}Fe_{0.93}Si₂, and AM Co_{0.07}Fe_{0.93}Si₂ obtained by refinements, together with their relative density obtained by the Archimede method.

	MR FeSi ₂	AM FeSi ₂	MR Co _{0.07} Fe _{0.93} Si ₂	AM Co _{0.07} Fe _{0.93} Si ₂
a (Å)	9.89104(6)	9.87518(4)	9.91176(8)	9.91200(4)
b (Å)	7.81612(3)	7.79980(3)	7.81410(4)	7.81500(4)
c (Å)	7.84209(3)	7.83727(2)	7.84084(5)	7.84060(3)
SF (%)	10.7(2)	3.7(1)	10.4(1)	3.2(1)
Rel. density (%)	94	97	94	97
Impurities (wt.%)	1 (FeSi)	1 (FeSi) 2.5 (Si)	2 (FeSi)	5 (FeSi)

Despite the phase transition from β -FeSi₂ to α -Fe_{1- δ} Si₂ during the sintering process

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3 and back to β -form after annealing, the microstructures of the densified materials remain
4 significantly different for the two synthesis routes. The MR samples are characterized by
5 smaller average particle sizes and higher density of grain boundaries, of porosities and higher
6 concentration of SF. All these defects acting at different scales in the materials are expected
7 to scatter efficiently the phonons over a broad energy spectrum and thus to reduce the
8 thermal conductivity of FeSi_2 . The influence of this microstructure on the thermoelectric
9 properties of this material is thus presented in the following.
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19 3.4 Thermoelectric properties

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21 The TE properties of $\beta\text{-FeSi}_2$ and $\beta\text{-Co}_{0.07}\text{Fe}_{0.93}\text{Si}_2$ synthesized by magnesioreduction and
22 arc-melting were investigated from room temperature up to 773 K. Measurements of the
23 electronic properties were cycled twice and showed good reversibility. Undoped MR $\beta\text{-FeSi}_2$
24 samples have elevated electrical resistivity ($14 \text{ m}\Omega \text{ m}$) (fig. 10a) and Seebeck coefficient
25 ($550 \mu\text{V K}^{-1}$) (fig. 10b) at room temperature which is in agreement with the relatively low
26 charge carrier concentration ($10^{17} - 10^{18} \text{ cm}^{-3}$) reported for this semiconductor.^{56,57} Interest-
27 ingly, the Seebeck coefficients are positive for MR and negative for AM samples indicating
28 n-type and p-type conductions, respectively. Experimental data from the literature report p-
29 type⁵⁸ as well as n-type^{14,27} bulk materials. The conduction type change is often attributed
30 to the presence of impurities or defects (*e.g.* Fe or Si vacancies), which strongly depends on
31 the synthesis route.⁵⁹ For instance Chu *et al.* also reported a change from p- to n-type con-
32 duction on a $\beta\text{-FeSi}_2$ thin film after prolonged annealing at 1163 K.⁶⁰ These results suggest
33 that the synthesis routes, as well as the high-temperature treatment, can strongly influence
34 the transport properties of $\beta\text{-FeSi}_2$ materials and possibly explain the different conduction
35 types measured in the present work. Due to its smaller electrical resistivity and despite its
36 smaller Seebeck coefficient, the PF of the MR $\beta\text{-FeSi}_2$ sample is found far superior to that
37 of the AM sample on the whole temperature range, reaching a maximum value of 0.2 mW
38 $\text{m}^{-1} \text{ K}^{-2}$ at 650 K (fig. 10c).
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Upon Co doping, the electrical resistivities of both MR and AM samples significantly drop while the Seebeck coefficient stabilizes around $-180 \mu\text{V K}^{-1}$. This can be explained by the creation of donor levels in the band gap⁶¹ increasing the estimated charge carriers concentration up to $10^{20} - 10^{21} \text{ cm}^{-3}$ according to literature data.^{58,62,63} The electrical resistivity of the MR sample is however systematically 35 % higher than the AM sample on the whole temperature range which can be partially explained by the lower density of the MR material.¹⁶ The resulting PF are increased to values as high as 0.9 and $1.0 \text{ mW m}^{-1} \text{ K}^{-2}$ at 773 K for the MR and AM $\beta\text{-Co}_{0.07}\text{Fe}_{0.93}\text{Si}_2$, respectively.

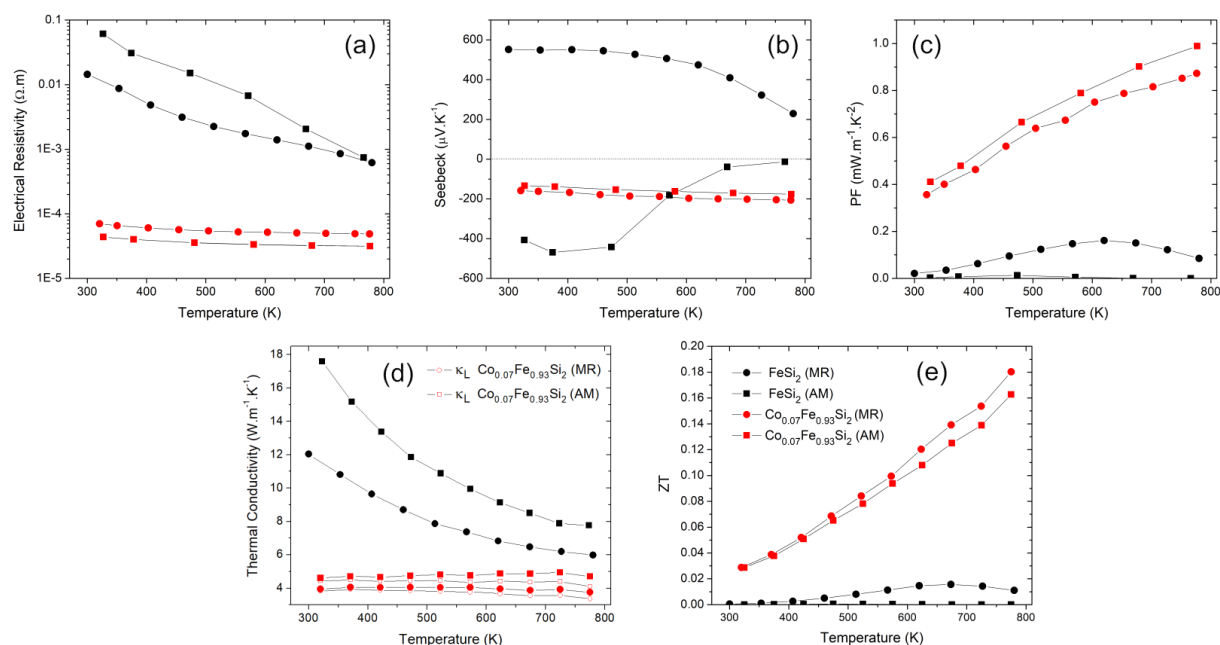


Figure 10: High temperature thermoelectric properties of $\beta\text{-FeSi}_2$ (black symbols) and $\beta\text{-Co}_{0.07}\text{Fe}_{0.93}\text{Si}_2$ (red symbols) synthesized by magnesio-reduction (MR, circles) and conventional arc-melting (AM, squares). Thermal dependence of (a) the electrical resistivity, (b) the thermopower, (c) the power factor (PF), (d) the total (filled symbols) and lattice (empty symbols) thermal conductivity and (e) resulting figure-of-merit ZT .

The thermal conductivities of AM $\beta\text{-FeSi}_2$ and $\beta\text{-Co}_{0.07}\text{Fe}_{0.93}\text{Si}_2$ (fig. 10d) equal 17.5 and $4.7 \text{ W m}^{-1} \text{ K}^{-1}$ at room temperature, which is in good agreement with most literature data.^{14,15,55,58} The lower thermal conductivity of the doped sample can be attributed to the mass fluctuation phenomenon at the mixed Fe/Co sites or to the scattering of phonons by polarons in these silicides.⁵⁸ The thermal conductivities of the respective MR synthesized

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3 samples are comparatively lower by 32 % and 15 % at 320 K. At the highest temperature,
4 the thermal conductivity reduction reaches 23 % for both compositions. The lattice thermal
5 conductivity of all the samples were estimated by subtraction of κ_E calculated with the
6 Wiedermann-Franz law $\kappa_e(T) = L \cdot T / \rho(T)$ with the commonly used $L = 2.4 \cdot 10^{-8} \text{ W } \Omega \text{ K}^{-2}$
7 to the total thermal conductivity. The lower κ measured for MR samples can thus be mostly
8 attributed to κ_L reduction reaching 24 % and 17 % at 773 K for the undoped and Co-doped
9 sample, respectively. The MR and AM samples have similar compositions, so the reduction
10 of κ_L is attributed to enhanced scattering at pores, grain boundaries and stacking faults,⁶⁴ all
11 of which occur in higher densities in the MR materials. Eventually, maximum figure-of-merit
12 ZT of 0.015 at 673 K and 0.18 at 773 K could be calculated for the undoped and doped MR
13 samples, respectively (fig. 10e). In the case of MR $\beta\text{-FeSi}_2$, ZT has been improved compared
14 to the AM sample mostly because of the reduced thermal conductivity, but it remains low
15 due to the exceedingly large electrical resistivity. On the other hand, MR $\beta\text{-Co}_{0.07}\text{Fe}_{0.93}\text{Si}_2$
16 has a much higher maximum ZT , which corresponds to a 12 % improvement compared to the
17 conventionally synthesized sample thanks to the mesostructuration. This value is to the best
18 of our knowledge among the highest ZT value reported at this temperature for Co-doped
19 $\beta\text{-FeSi}_2$.^{15,65}

40 **4 Conclusions**

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42 An optimized magnesio-reduction synthesis of $\beta\text{-FeSi}_2$ and $\beta\text{-Co}_{0.07}\text{Fe}_{0.93}\text{Si}_2$ powders from
43 (Co-doped) Fe_2O_3 and Si has been developed. It offers many advantages over more conven-
44 tional synthesis routes such as the use of air-stable and inexpensive precursors, short heat
45 treatment below the decomposition temperature of $\beta\text{-FeSi}_2$, very high yield (> 98 %) and
46 a satisfying control of the chemical composition including dopant concentration. Detailed
47 study of the reaction mechanism by means of XRD pattern Rietveld refinements enabled
48 to determine the reduction starting temperature between 923 K and 973 K, the formation
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3 of Mg₂Si intermediate during the process, and a total duration of the thermal treatment of
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5 19 h to achieve a total reaction. After removal of MgO by-product by diluted HCl wash-
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7 ing, the as-synthesized silicide powders are composed of well-crystallized grains with sizes
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9 ranging between 30 and 400 nm. TEM observations reveal high concentration of stacking
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11 faults evaluated at 15 - 18 % by refinement of the XRD pattern using a dedicated software.
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13 The high temperature TE properties of MR/SPS/annealed densified pellets were measured
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15 up to 773 K and compared to conventionally AM/SPS/annealed samples with similar com-
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17 positions. The higher densities of grain boundaries, stacking faults and porosities in the
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19 magnesio-reduced materials lead to strongly reduced lattice thermal conductivities. As a re-
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21 sult, the TE figures-of-merit ZT of the two compositions are improved, even reaching 0.18
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23 at 773 K in the case of β -Co_{0.07}Fe_{0.93}Si₂.
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26 27 28 **5 Conflicts of interest**

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31 There are no conflicts to declare.
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34 35 **Acknowledgement**

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51 52 **Supporting Information Available**

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55 • Figure SI 1: Le Bail refined XRD pattern of the Co_{0.14}Fe_{1.86}O₃ precursor;

- Figure SI 2: Rietveld refined XRD patterns of the samples at various stages of the reaction;
- Tables SI 1-9: Tables summarizing the refined parameters obtained from the refined patterns shown in figure SI 2;
- Figure SI 3: FAULTS refined XRD patterns of the sintered MR and AM β -Co_{0.07}Fe_{0.93}Si₂ samples;
- Table SI 10: Summary of the refined parameters obtained for the sintered β -FeSi₂ and β -Co_{0.07}Fe_{0.93}Si₂ XRD patterns synthesized from MR and AM routes.

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